



Solution synthesis of CuSbS₂ nanocrystals: A new approach to control shape and size



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ABSTRACT

Chalcostibite copper antimony sulfide (CuSbS₂) micro- and nanoparticles with a different shape and size have been prepared by a new approach to hot injection route. In this method, sulfur in oleylamine (OLA) is employed as a sulfonating agent providing a simple route to control the shape and size of the particles, which enables the optimization of CuSbS₂ for a variety of applications. The sulfur to metallic precursor ratio appears to be one of the most effective parameters along with the temperature and time for controlling the size and morphology of the particles. The growth mechanism study shows in addition to the CuSbS₂ phase the presence of not previously observed intermediate phases (stibnite (Sb₂S₃) and famatinite (Cu₃SbS₄)) at the initial stage of the reaction. By increasing the ratio of sulfur to copper and antimony, wider and thinner CuSbS₂ particles are obtained. The particles have nanoplate and nanosheet morphology with a good shape and size uniformity. Coalescence of very thin nanosheets occurs with increasing reaction time eventually leading to formation of thicker particles which can be called nanobricks. Band gap determinations demonstrate that the obtained CuSbS₂ particles have both direct (1.51–1.57 eV) and indirect (1.44–1.51 eV) bandgaps. Transmission Electron Microscopy (TEM) studies revealed that the preferred growth directions are along the basis axes of the unit cell ([100] and [010]). Optical and structural properties of the obtained CuSbS₂ particles are indicative for their great potential in different generations of solar cells and supercapacitor applications.

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1. Introduction

Semiconductor nanocrystals have attracted considerable attention owing to their wide range of applications in photodetectors [1–3], light emitting diodes [4,5], biology [6] supercapacitors [7,8], and solar cells [9–11]. Different kinds of semiconductors have been developed for each purpose [12]. Interesting candidates among those specifically aimed for solar cell applications are ternary and quaternary copper-based chalcogenide semiconductors, because they have high absorption coefficients and appropriate band gaps for light absorption. Within ternary chalcogenide semiconductors chalcostibite (CuSbS₂) is an emerging one due to its suitable bandgap. It is relatively less explored in comparison with CuInS₂

[13,14], Cu(InGa)Se₂ [15], and Cu₂ZnSnS₄ [16,17] and has been demonstrated as a promising alternative, because all elemental components of CuSbS₂ are earth abundant and economical, as the price of antimony is much lower than that of indium [18]. First-principle calculations using density functional theory have indicated CuSbS₂ as a new promising candidate for a p-type absorber material [19]. The results of the calculations suggest that CuSbS₂ has a strong light absorption coefficient ($\alpha > 1 \times 10^4 \text{ cm}^{-1}$), and suitable electrical properties, both of which are essential for solar cell application [20,21]. CuSbS₂ crystallizes in an orthorhombic crystal system with a *Pnma* space group [22]. It is chemically quite similar to CuInS₂ but structurally very different due to its low valence state of antimony [23]. Theoretical simulations predict that CuSbS₂ has an indirect band gap, but experimental investigations show that the material has a direct band gap. However, many key parameters of CuSbS₂, such as the conduction band and valence band positions have not been fully investigated [21,24]. Studies of

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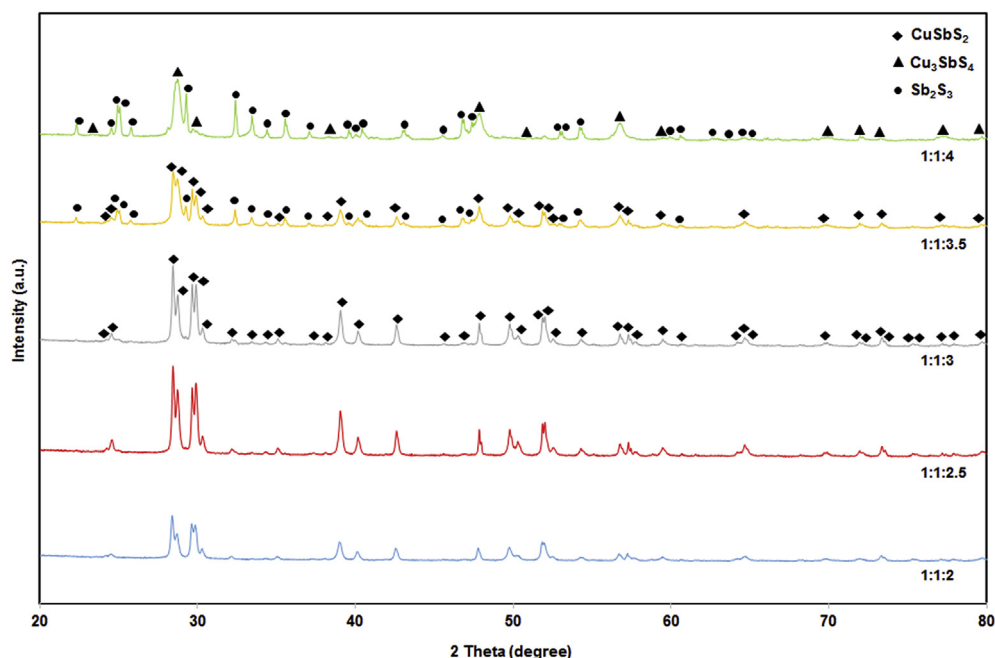


Fig. 1. XRD patterns of powders synthesized at 260 °C with different sulfur ratios.

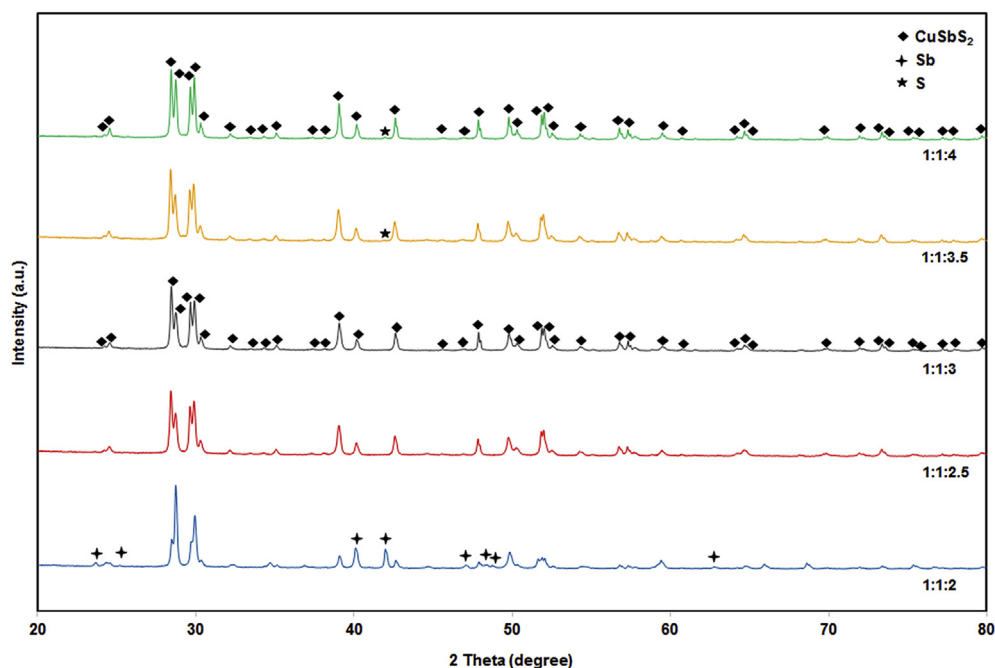


Fig. 2. XRD patterns of powders synthesized at 260 °C with different sulfur ratios.

this material as a potential absorber for sustainable and scalable thin film solar cells have been conducted, but still more research and investigation needs to be done in order to fully characterize the

Table 1
Summary of powder X-ray diffraction measurements for samples.

Sample	Cu:Sb:S	Reaction temperature (T) (°C)	a (Å)	b (Å)	c (Å)
A	1:1:2	240	6.021	3.801	14.505
B	1:1:2.5	240	6.024	3.800	14.506
C	1:1:3	240	6.024	3.800	14.504
D	1:1:2.5	260	6.024	3.800	14.507
E	1:1:3	260	6.023	3.798	14.503

properties of these materials [25–28].

In recent years, characterization of CuSbS₂ thin films deposited by sputtering [29], thermal evaporation [30,31], and chemical bath deposition [32] have been published, but there are only a few studies on the synthesis of CuSbS₂ in powder form. In the synthesis of ternary materials, controlling the reaction condition, which is directly related to the synthesis method is essential. Many efforts have been focused on the nanoparticle formation mechanism, and many reliable and reproducible synthesis approaches have been developed [33,34]. Solvothermal, hydrothermal and hot injection methods have already been reported for the formation of CuSbS₂

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